

S4A THRU S4M

4.0 AMPS. Surface Mount Rectifiers



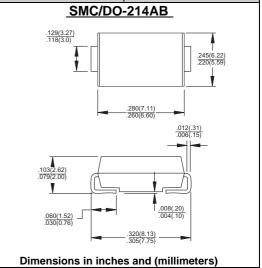
Voltage Range 50 to 1000 Volts Current 4.0 Amperes

Features

- ♦ For surface mounted application
- Glass passivated junction chip.
- ♦ Low forward voltage drop
- High current capability
- ♦ Easy pick and place
- ♦ High surge current capability
- Plastic material used carries Underwriters Laboratory Classification 94V-O
- High temperature soldering:
- ♦ 260°C / 10 seconds at terminals

Mechanical Data

- Case: Molded plasticTerminals: Solder plated
- ♦ Polarity: Indicated by cathode band
- ♦ Packaging: 16mm tape per EIA STD RS-481
- Weight: 0.21 gram



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| To Supulity Toda, dorate surrent by 2070 | | | | | | | | | |
|--|-------------------------------|-------------|-----|-----|-----|-----|-----|------|-------------|
| Type Number | Symbol | S4A | S4B | S4D | S4G | S4J | S4K | S4M | Units |
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current @T _L =75°C | I _(AV) | 4.0 | | | | | | | Α |
| Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I _{FSM} | 100 | | | | | | | Α |
| Maximum Instantaneous Forward Voltage @ 4.0A | V _F | 1.15 | | | | | | | V |
| Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =125°C | I _R | 10.0 250 | | | | | | | uA uA |
| Typical Thermal Resistance (Note 3) | $R\theta_{JL}$ $R\theta_{JA}$ | 13 47 | | | | | | | C /W |
| Maximum Reverse Recovery Time (Note 1) | Trr | 2.5 | | | | | | | uS |
| Typical Junction Capacitance (Note 2) | Cj | 60 | | | | | | | рF |
| Operating Temperature Range | TJ | -55 to +150 | | | | | | | Ą |
| Storage Temperature Range | T _{STG} | -55 to +150 | | | | | | | Q |

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

- 2. Measured at 1 MHz and Applied V_R=4.0 Volts
- 3. Measured on P.C. Board with 0.6 x 0.6" (16 x 16mm) Copper Pad Areas.



